L Number	Hits	Search Text	DB	TT:mo at
1	38757		USPAT;	Time stamp 2003/03/27 10:17
4		1	US-PGPUB;	2003/03/2/ 10:1/
			EPO; JPO;	
1		1	DERWENT;	1
t	j		IBM TDB	
2	133992	((contact conduct\$3) near (via hole plug))	USPAT:	2002/02/27 12 22
		((to made of solidate to sol	/	2003/03/27 10:20
			US-PGPUB;	
			EPO; JPO;	1
			DERWENT;	İ
3	9363	(wiring near layer) and (((contact	IBM_TDB	
<u> </u>	, ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	conduct\$3) near (via hole plug)))	USPAT;	2003/03/27 10:20
	1	(Via Noie plug))	US-PGPUB;	j
1			EPO; JPO;	İ
1			DERWENT;	
4	8109	//wining many laws when the control of the control	IBM_TDB	
5	0109	((wiring near layer) and (((contact	USPAT;	2003/03/27 10:21
		conduct\$3) near (via hole plug)))) and	US-PGPUB;	
	1	(insulat\$3 dielectric)	EPO; JPO;	
			DERWENT;	
	4000		IBM_TDB	†
	4080	(((wiring near layer) and (((contact	USPAT;	2003/03/27 10:21
		conduct\$3) near (via hole plug)))) and	US-PGPUB;	1
} 	1	(insulat\$3 dielectric)) and gate	PPO; JPO;	
İ			DERWENT;	1
ا ر	2020		IBM_TDB	}
6	3939	((((wiring near layer) and (((contact	USPAT;	2003/03/27 10:23
·		conduct\$3) near (via hole plug)))) and	US-PGPUB;	<u> </u>
;		(insulat\$3 dielectric)) and gate) and	EPO; JPO;	l t
) 	,	(substrate base)	DERWENT;	
7 :	0050		IBM_TDB	
. <i>'</i>	2852	(((((wiring near layer) and (((contact	USPAT;	2003/03/27 10:25
		conduct\$3) near (via hole plug)))) and	US-PGPUB;	
		(insulat\$3 dielectric)) and gate) and	EPO; JPO;	1
		(substrate base)) and (source and drain)	DERWENT;	
			IBM TDB	l
8	1802	(((((wiring near layer) and (((contact	USPĀT;	2003/03/27 10:25
		conduct\$3) near (via hole plug)))) and	US-PGPUB;	
	1	(insulat\$3 dielectric)) and gate) and	EPO; JPO;	
ļ		(substrate base)) and (source and drain))	DERWENT;	
		and (gate near insulat\$3)	IBM TDB	